MOSFETs Silicon N-Channel MOS (DTMOS II)

TK12E60U

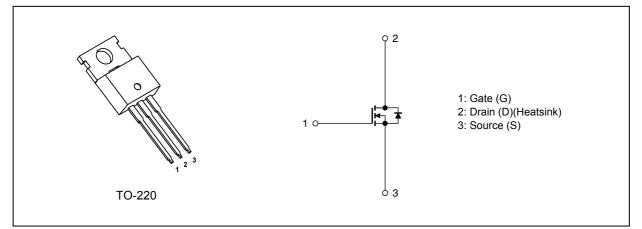
1. Applications

Switching Voltage Regulators

2. Features

- (1) Low drain-source on-resistance: $R_{DS(ON)} = 0.36 \Omega$ (typ.)
- (2) High forward transfer admittance: $|Y_{fs}| = 7.0 \text{ S}$ (typ.)
- (3) Low leakage current: I_{DSS} = 100 μ A (max) (V_{DS} = 600 V)
- (4) Enhancement mode: V_{th} = 3.0 to 5.0 V (V_{DS} = 10 V, I_D = 1 mA)

3. Packaging and Internal Circuit



4. Absolute Maximum Ratings (Note) ($T_a = 25^{\circ}C$ unless otherwise specified)

Characteristics	Symbol	Rating	Unit	
Drain-source voltage		V _{DSS}	600	V
Gate-source voltage		V _{GSS}	±30	
Drain current (DC)	(Note 1)	Ι _D	12	A
Drain current (pulsed)	(Note 1)	I _{DP}	24	
Power dissipation	(T _c = 25°C)	PD	144	W
Single-pulse avalanche energy	(Note 2)	E _{AS}	69	mJ
Avalanche current	(Note 3)	I _{AR}	6	A
Repetitive avalanche energy	(Note 3)	E _{AR}	14	mJ
Reverse drain current (DC)	(Note 1)	I _{DR}	12	A
Reverse drain current (pulsed)	(Note 1)	I _{DRP}	24	
Channel temperature		T _{ch}	150	°C
Storage temperature		T _{stg}	-55 to 150	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Start of commercial production

5. Thermal Characteristics

Characteristics	Symbol	Max	Unit
Channel-to-case thermal resistance	R _{th(ch-c)}	0.868	°C/W
Channel-to-ambient thermal resistance	R _{th(ch-a)}	83.3	

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: V_{DD} = 90 V, T_{ch} = 25°C (initial), L = 3.39 mH, R_G = 25 Ω , I_{AR} = 6 A

Note 3: Repetitive rating; pulse width limited by maximum channel temperature

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

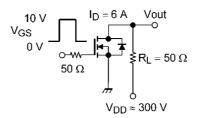
6. Electrical Characteristics

6.1. Static Characteristics (Ta = 25°C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current	I _{GSS}	V_{GS} = ±30 V, V_{DS} = 0 V	_	_	±1	μA
Drain cut-off current	I _{DSS}	V _{DS} = 600 V, V _{GS} = 0 V	_	_	100	
Drain-source breakdown voltage	V _{(BR)DSS}	I _D = 10 mA, V _{GS} = 0 V	600	_	—	V
Gate threshold voltage	V _{th}	V _{DS} = 10 V, I _D = 1 mA	3.0	_	5.0	
Drain-source on-resistance	R _{DS(ON)}	V _{GS} = 10 V, I _D = 6 A	_	0.36	0.4	Ω
Forward transfer admittance	Y _{fs}	V _{DS} = 10 V, I _D = 6 A	2.0	7.0	_	S

6.2. Dynamic Characteristics ($T_a = 25^{\circ}C$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Input capacitance	C _{iss}	V _{DS} = 10 V, V _{GS} = 0 V, f = 1 MHz	_	720	_	pF
Reverse transfer capacitance	C _{rss}		_	55	_	
Output capacitance	C _{oss}			1700	_	
Switching time (rise time)	t _r	See Figure 6.2.1		30	_	ns
Switching time (turn-on time)	t _{on}		_	60	_	
Switching time (fall time)	t _f			8	_	
Switching time (turn-off time)	t _{off}		_	75	_	



Duty \leq 1%, $t_W =$ 10 μs

Fig. 6.2.1 Switching Time Test Circuit

6.3. Gate Charge Characteristics ($T_a = 25^{\circ}C$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Total gate charge (gate-source plus gate-drain)	Qg	$V_{DD} \approx 400 \text{ V}, V_{GS} \text{ = } 10 \text{V}, \text{I}_{\text{D}} \text{ = } 12 \text{A}$	_	14	—	nC
Gate-source charge	Q _{gs}		_	8.5	_	
Gate-drain charge	Q _{gd}			5.5	_	

6.4. Source-Drain Characteristics ($T_a = 25^{\circ}C$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Diode forward voltage	V _{DSF}	I _{DR} = 12 A, V _{GS} = 0 V	_	—	-1.7	V
Reverse recovery time	t _{rr}	I _{DR} = 12 A, V _{GS} = 0 V	_	380	_	ns
Reverse recovery charge	Q _{rr}	-dI _{DR} /dt = 100 A/μs	_	5.3	_	μC

7. Marking

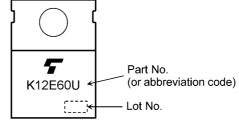
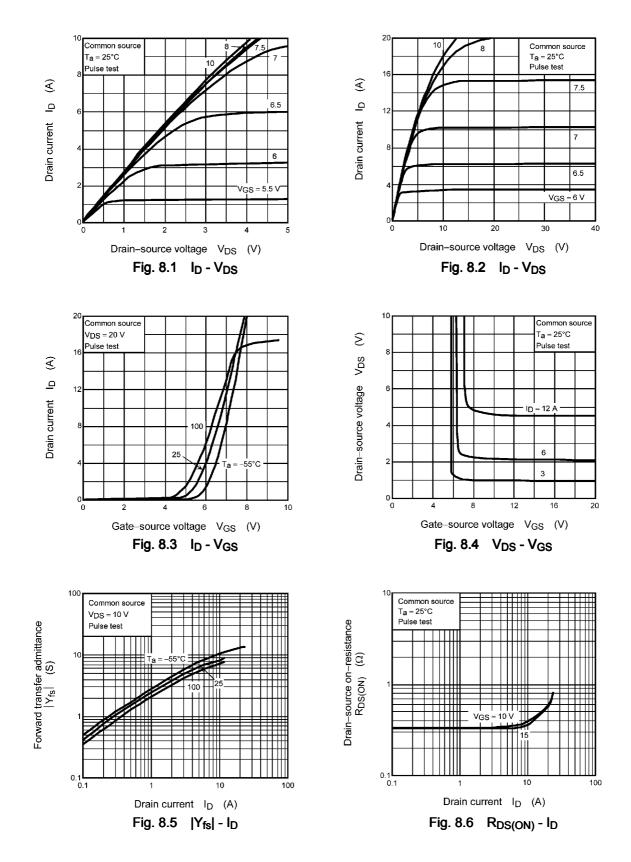
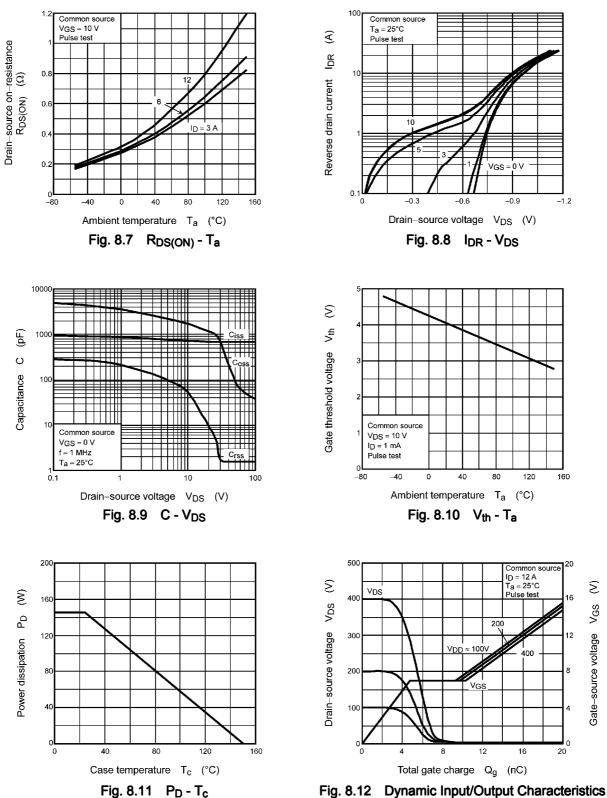


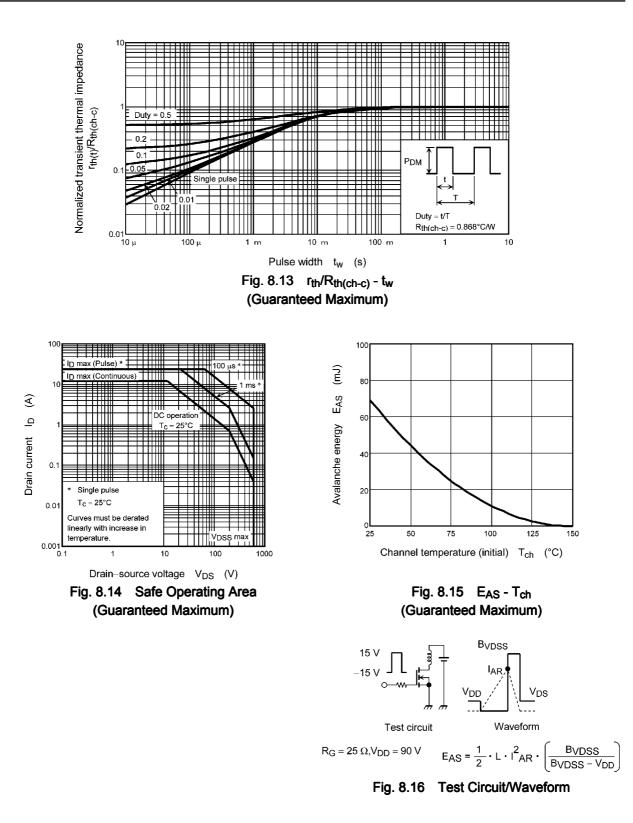
Fig. 7.1 Marking

8. Characteristics Curves (Note)





(Guaranteed Maximum)

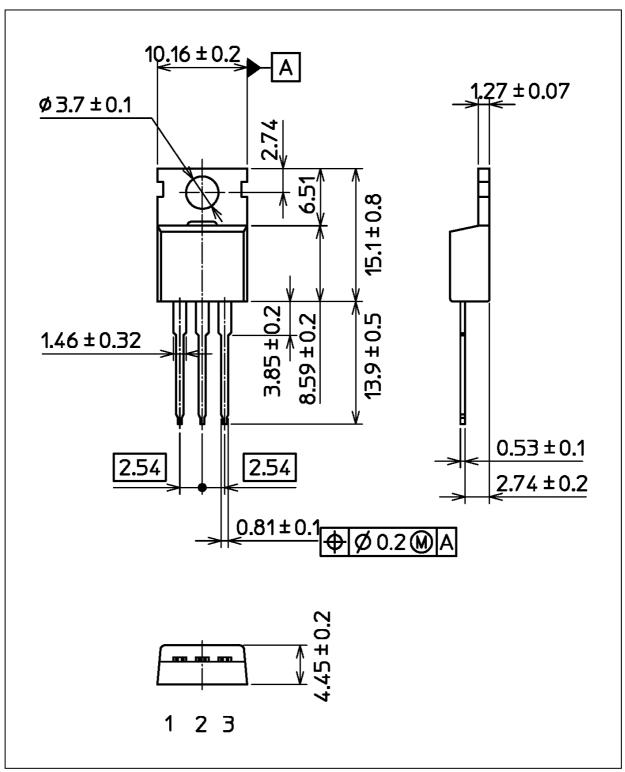


Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

Package Dimensions

TK12E60U





Weight: 1.93 g (typ.)

	Package Name(s)
TOSHIBA: 2-10X1A	
Nickname: TO-220	

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